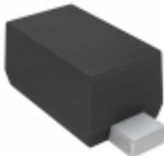
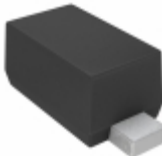
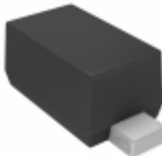
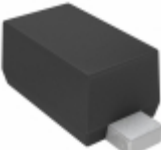
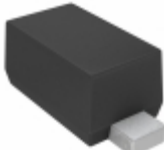
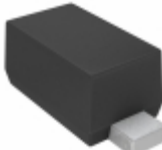
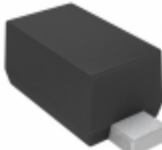


specificazioni	
Numero di parte	CDZVT2R5.6B
fabbricante	LAPIS Semiconductor
Descrizione	DIODE ZENER 5.6V 100MW VMN2M
Categoria	Prodotti a semiconduttore discreti > Diodi - Zener -
Stato parte	16000 pcs Stock
Serie	-
temperatura di esercizio	150°C
Tipo montaggio	Surface Mount
Potenza - Max	100mW
Tolleranza	-
Contenitore / involucro	2-SMD, Flat Lead
Contenitore dispositivo fornitore	VMN2M
Tensione - diretta (Vf) (max) a If	-
Corrente - Dispersione inversa a Vr	1µA @ 2.5V
Tensione - Zener (Nom) (Vz)	5.6V
Impedenza (Max) (zzt)	60 Ohm
imballaggio	Tape & Reel (TR)

 CDZVT2R6.2B LAPIS Semiconductor DIODE ZENER 6.2V 100MW VMN2M	 CDZVT2R6.8B LAPIS Semiconductor DIODE ZENER 6.8V 100MW VMN2M	 CDZVT2R36B LAPIS Semiconductor DIODE ZENER 36V 100MW VMN2M	 CDZVT2R4.7B LAPIS Semiconductor DIODE ZENER 4.7V 100MW VMN2M
 CDZVT2R5.1B LAPIS Semiconductor DIODE ZENER 5.1V 100MW VMN2M	 CDZVT2R4.3B LAPIS Semiconductor DIODE ZENER 4.3V 100MW VMN2M	 CDZVT2R7.5B LAPIS Semiconductor DIODE ZENER 7.5V 100MW VMN2M	 CDZVT2R33B LAPIS Semiconductor DIODE ZENER 33V 100MW VMN2M

Di Più

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